NSN 5961-01-182-8222

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-182-8222 **Inclosure Material:** Glass **Overall Length:** 0.265 inches **Terminal Length:** 1.250 inches **Overall Diameter:** 0.096 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case and burn in **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 reverse voltage, dc and 30.0 working peak reverse voltage **Current Rating Per Characteristic:** 500.00 milliamperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Test Data Document:** 53711-5169667 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No